

# TPIC6B596 POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

- Low  $r_{DS(on)}$  . . . 5  $\Omega$
- Avalanche Energy . . . 30 mJ
- Eight Power DMOS-Transistor Outputs of 150-mA Continuous Current
- 500-mA Typical Current-Limiting Capability
- Output Clamp Voltage . . . 50 V
- Enhanced Cascading for Multiple Stages
- All Registers Cleared With Single Input
- Low Power Consumption

## description

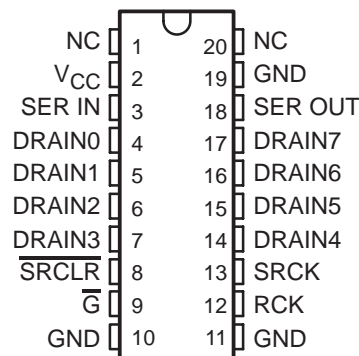
The TPIC6B596 is a monolithic, high-voltage, medium-current power 8-bit shift register designed for use in systems that require relatively high load power. The device contains a built-in voltage clamp on the outputs for inductive transient protection. Power driver applications include relays, solenoids, and other medium-current or high-voltage loads.

This device contains an 8-bit serial-in, parallel-out shift register that feeds an 8-bit D-type storage register. Data transfers through both the shift and storage registers on the rising edge of the shift-register clock (SRCK) and the register clock (RCK), respectively. The storage register transfers data to the output buffer when shift-register clear ( $\overline{SRCLR}$ ) is high. When  $\overline{SRCLR}$  is low, all registers in the device are cleared. When output enable ( $\overline{G}$ ) is held high, all data in the output buffers is held low and all drain outputs are off. When  $\overline{G}$  is held low, data from the storage register is transparent to the output buffers. When data in the output buffers is low, the DMOS-transistor outputs are off. When data is high, the DMOS-transistor outputs have sink-current capability. The serial output (SER OUT) is clocked out of the device on the falling edge of SRCK to provide additional hold time for cascaded applications. This will provide improved performance for applications where clock signals may be skewed, devices are not located near one another, or the system must tolerate electromagnetic interference.

Outputs are low-side, open-drain DMOS transistors with output ratings of 50 V and 150-mA continuous sink-current capability. Each output provides a 500-mA typical current limit at  $T_C = 25^\circ\text{C}$ . The current limit decreases as the junction temperature increases for additional device protection.

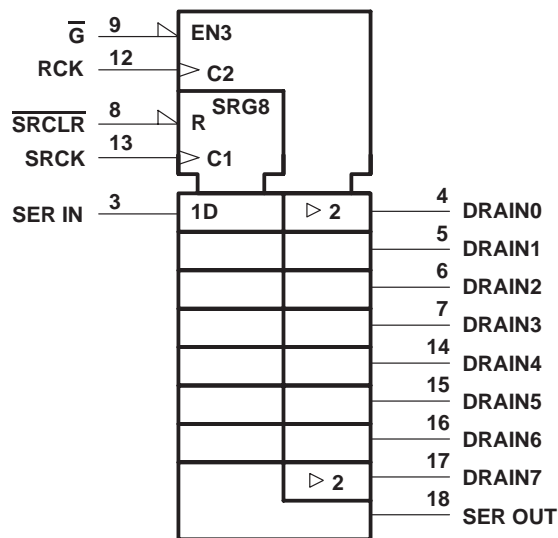
The TPIC6B596 is characterized for operation over the operating case temperature range of  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .

DW OR N PACKAGE  
(TOP VIEW)



NC – No internal connection

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS  
INSTRUMENTS**

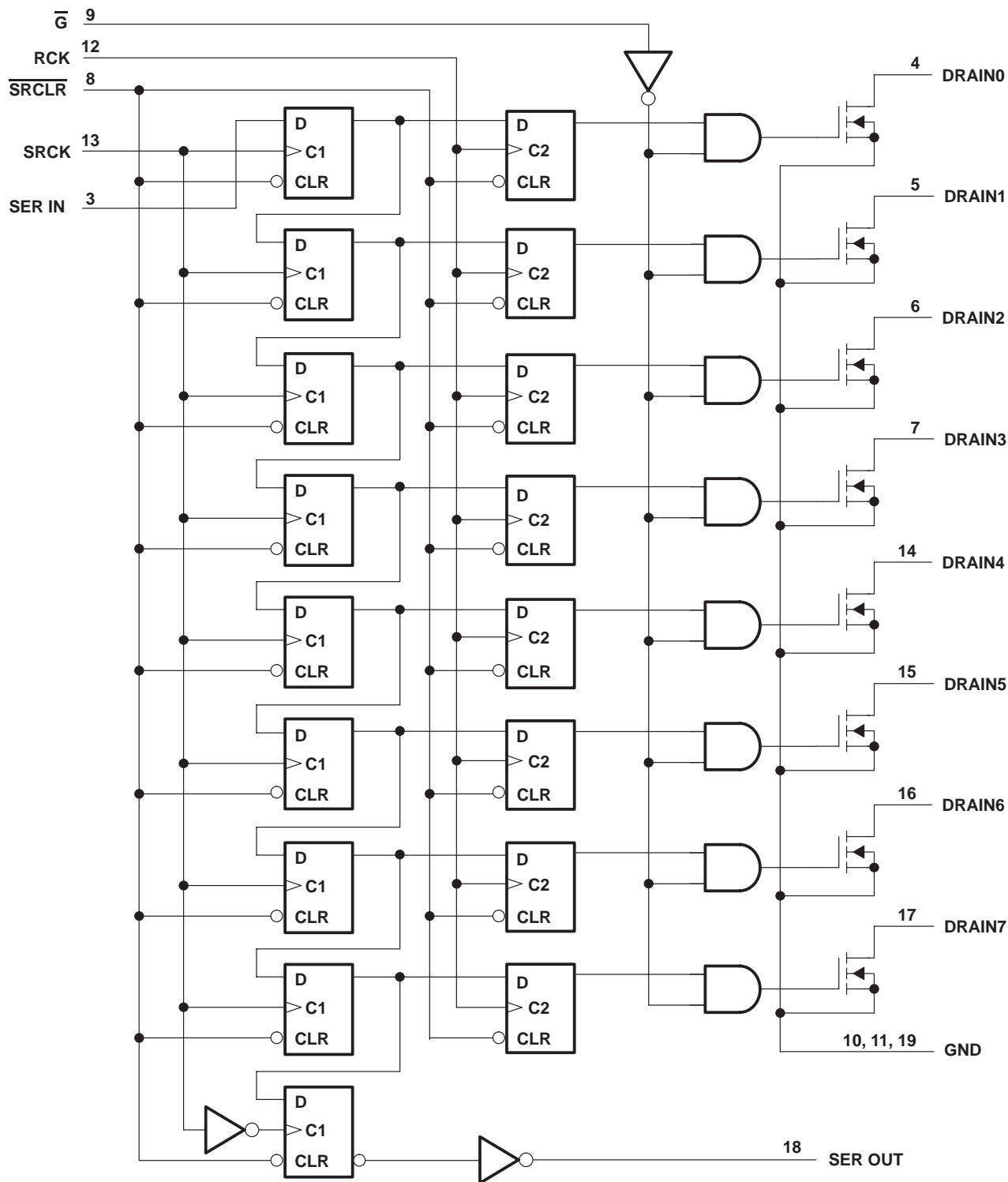
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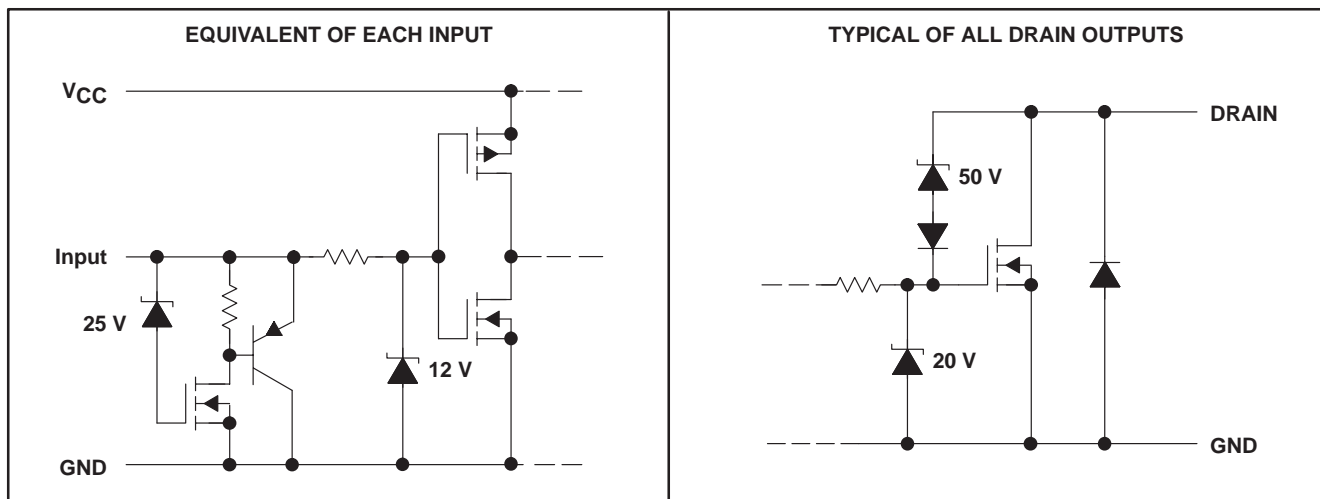
# TPIC6B596 POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

## logic diagram (positive logic)



**schematic of inputs and outputs**



**absolute maximum ratings over recommended operating case temperature range (unless otherwise noted)†**

Logic supply voltage, $V_{CC}$ (see Note 1)	7 V
Logic input voltage range, $V_I$	-0.3 V to 7 V
Power DMOS drain-to-source voltage, $V_{DS}$ (see Note 2)	50 V
Continuous source-to-drain diode anode current	500 mA
Pulsed source-to-drain diode anode current (see Note 3)	1 A
Pulsed drain current, each output, all outputs on, $I_D$ , $T_C = 25^\circ\text{C}$ (see Note 3)	500 mA
Continuous drain current, each output, all outputs on, $I_D$ , $T_C = 25^\circ\text{C}$	150 mA
Peak drain current single output, $I_{DM}$ , $T_C = 25^\circ\text{C}$ (see Note 3)	500 mA
Single-pulse avalanche energy, $E_{AS}$ (see Figure 4)	30 mJ
Avalanche current, $I_{AS}$ (see Note 4)	500 mA
Continuous total dissipation	See Dissipation Rating Table
Operating virtual junction temperature range, $T_J$	-40°C to 150°C
Operating case temperature range, $T_C$	-40°C to 125°C
Storage temperature range	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values are with respect to GND.
  2. Each power DMOS source is internally connected to GND.
  3. Pulse duration  $\leq 100 \mu\text{s}$  and duty cycle  $\leq 2\%$ .
  4. DRAIN supply voltage = 15 V, starting junction temperature ( $T_{JS}$ ) = 25°C,  $L = 200 \text{ mH}$ ,  $I_{AS} = 0.5 \text{ A}$  (see Figure 4).

**DISSIPATION RATING TABLE**

PACKAGE	$T_C \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_C = 25^\circ\text{C}$	$T_C = 125^\circ\text{C}$ POWER RATING
DW	1389 mW	11.1 mW/°C	278 mW
N	1050 mW	10.5 mW/°C	263 mW

# TPIC6B596

## POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

### recommended operating conditions

	MIN	MAX	UNIT
Logic supply voltage, $V_{CC}$	4.5	5.5	V
High-level input voltage, $V_{IH}$	0.85 $V_{CC}$		V
Low-level input voltage, $V_{IL}$	0.15 $V_{CC}$		V
Pulsed drain output current, $T_C = 25^\circ\text{C}$ , $V_{CC} = 5\text{ V}$ (see Notes 3 and 5)	-500	500	mA
Setup time, SER IN high before SRCK $\uparrow$ , $t_{SU}$ (see Figure 2)	15		ns
Hold time, SER IN high after SRCK $\uparrow$ , $t_H$ (see Figure 2)	15		ns
Pulse duration, $t_W$ (see Figure 2)	40		ns
Operating case temperature, $T_C$	-40	125	$^\circ\text{C}$

NOTES: 3. Pulse duration  $\leq 100\ \mu\text{s}$  and duty cycle  $\leq 2\%$ .  
5. Technique should limit  $T_J - T_C$  to  $10^\circ\text{C}$  maximum.

### electrical characteristics, $V_{CC} = 5\text{ V}$ , $T_C = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$V_{(BR)DSX}$ Drain-to-source breakdown voltage	$I_D = 1\text{ mA}$	50			V	
$V_{SD}$ Source-to-drain diode forward voltage	$I_F = 100\text{ mA}$		0.85	1	V	
$V_{OH}$ High-level output voltage, SER OUT	$I_{OH} = -20\ \mu\text{A}$ , $V_{CC} = 4.5\text{ V}$	4.4	4.49		V	
	$I_{OH} = -4\text{ mA}$ , $V_{CC} = 4.5\text{ V}$	4	4.2			
$V_{OL}$ Low-level output voltage, SER OUT	$I_{OL} = 20\ \mu\text{A}$ , $V_{CC} = 4.5\text{ V}$		0.005	0.1	V	
	$I_{OL} = 4\text{ mA}$ , $V_{CC} = 4.5\text{ V}$		0.3	0.5		
$I_{IH}$ High-level input current	$V_{CC} = 5.5\text{ V}$ , $V_I = V_{CC}$			1	$\mu\text{A}$	
$I_{IL}$ Low-level input current	$V_{CC} = 5.5\text{ V}$ , $V_I = 0$			-1	$\mu\text{A}$	
$I_{CC}$ Logic supply current	$V_{CC} = 5.5\text{ V}$	All outputs off	20	100	$\mu\text{A}$	
		All outputs on	150	300		
$I_{CC}(\text{FRQ})$ Logic supply current at frequency	$f_{SRCK} = 5\text{ MHz}$ , $C_L = 30\text{ pF}$ , All outputs off, See Figures 2 and 6		0.4	5	mA	
$I_N$ Nominal current	$V_{DS(\text{on})} = 0.5\text{ V}$ , $I_N = I_D$ , $T_C = 85^\circ\text{C}$	See Notes 5, 6, and 7		90	mA	
$I_{DSX}$ Off-state drain current	$V_{DS} = 40\text{ V}$ , $V_{CC} = 5.5\text{ V}$		0.1	5	$\mu\text{A}$	
	$V_{DS} = 40\text{ V}$ , $V_{CC} = 5.5\text{ V}$ , $T_C = 125^\circ\text{C}$		0.15	8		
$r_{DS(\text{on})}$ Static drain-source on-state resistance	$I_D = 100\text{ mA}$ , $V_{CC} = 4.5\text{ V}$	See Notes 5 and 6 and Figures 7 and 8		4.2	5.7	$\Omega$
	$I_D = 100\text{ mA}$ , $T_C = 125^\circ\text{C}$ , $V_{CC} = 4.5\text{ V}$			6.8	9.5	
	$I_D = 350\text{ mA}$ , $V_{CC} = 4.5\text{ V}$			5.5	8	

NOTES: 5. Technique should limit  $T_J - T_C$  to  $10^\circ\text{C}$  maximum.  
6. These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.  
7. Nominal current is defined for a consistent comparison between devices from different sources. It is the current that produces a voltage drop of 0.5 V at  $T_C = 85^\circ\text{C}$ .



**switching characteristics,  $V_{CC} = 5\text{ V}$ ,  $T_C = 25^\circ\text{C}$**

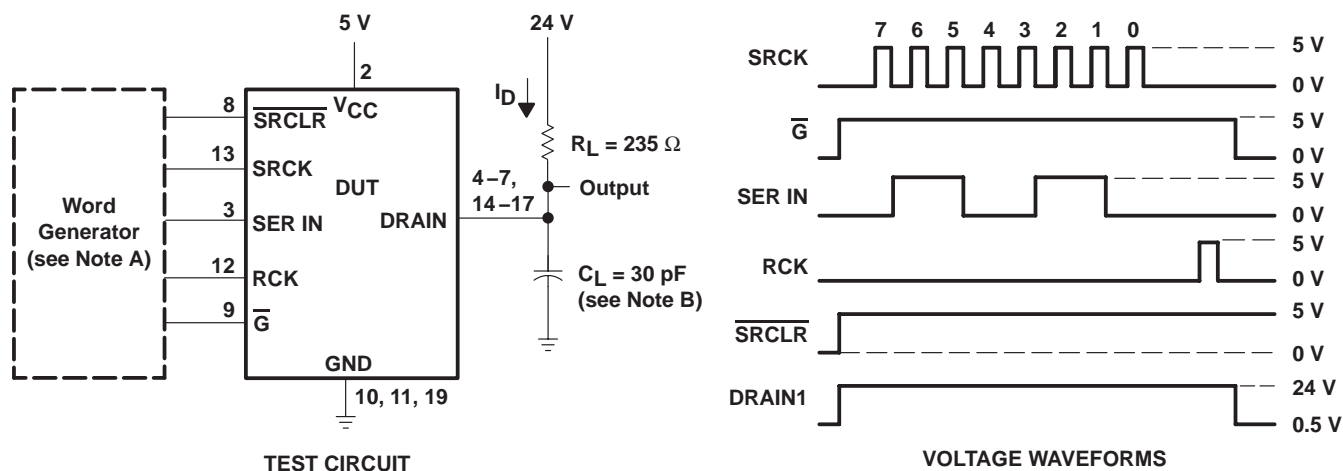
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$	Propagation delay time, low-to-high-level output from $\overline{G}$	$C_L = 30\text{ pF}$ , $I_D = 100\text{ mA}$ , See Figures 1, 2, and 9		150		ns
$t_{PHL}$	Propagation delay time, high-to-low-level output from $\overline{G}$			90		ns
$t_r$	Rise time, drain output			200		ns
$t_f$	Fall time, drain output			200		ns
$t_{pd}$	Propagation delay time, SRCK $\downarrow$ to SEROUT	$C_L = 30\text{ pF}$ , See Figure 2		15		ns
$f(\text{SRCK})$	Serial clock frequency	$C_L = 30\text{ pF}$ , See Note 8			10	MHz
$t_a$	Reverse-recovery-current rise time	$I_F = 100\text{ mA}$ , $di/dt = 20\text{ A}/\mu\text{s}$ , See Notes 5 and 6 and Figure 3		100		ns
$t_{rr}$	Reverse-recovery time			300		

- NOTES: 5. Technique should limit  $T_J - T_C$  to  $10^\circ\text{C}$  maximum.  
 6. These parameters are measured with voltage-sensing contacts separate from the current-carrying contacts.  
 8. This is the maximum serial clock frequency assuming cascaded operation where serial data is passed from one stage to a second stage. The clock period allows for SRCK  $\rightarrow$  SEROUT propagation delay and setup time plus some timing margin.

**thermal resistance**

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
$R_{\theta JA}$	Thermal resistance, junction-to-ambient	DW package		90	$^\circ\text{C}/\text{W}$
		N package		95	

**PARAMETER MEASUREMENT INFORMATION**



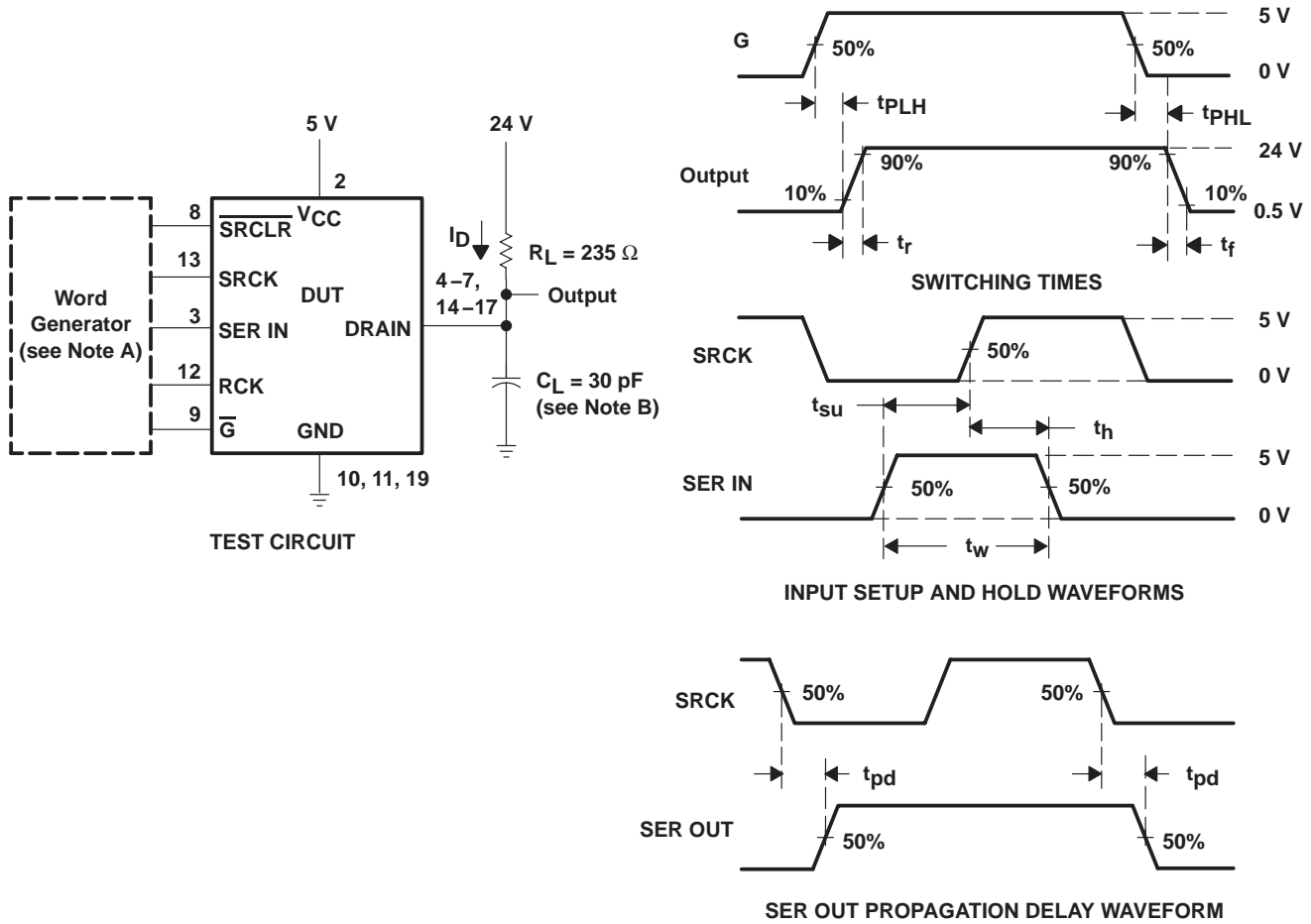
- NOTES: A. The word generator has the following characteristics:  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$ ,  $t_w = 300\text{ ns}$ , pulsed repetition rate (PRR) = 5 kHz,  $Z_O = 50\ \Omega$ .  
 B.  $C_L$  includes probe and jig capacitance.

**Figure 1. Resistive-Load Test Circuit and Voltage Waveforms**

# TPIC6B596 POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

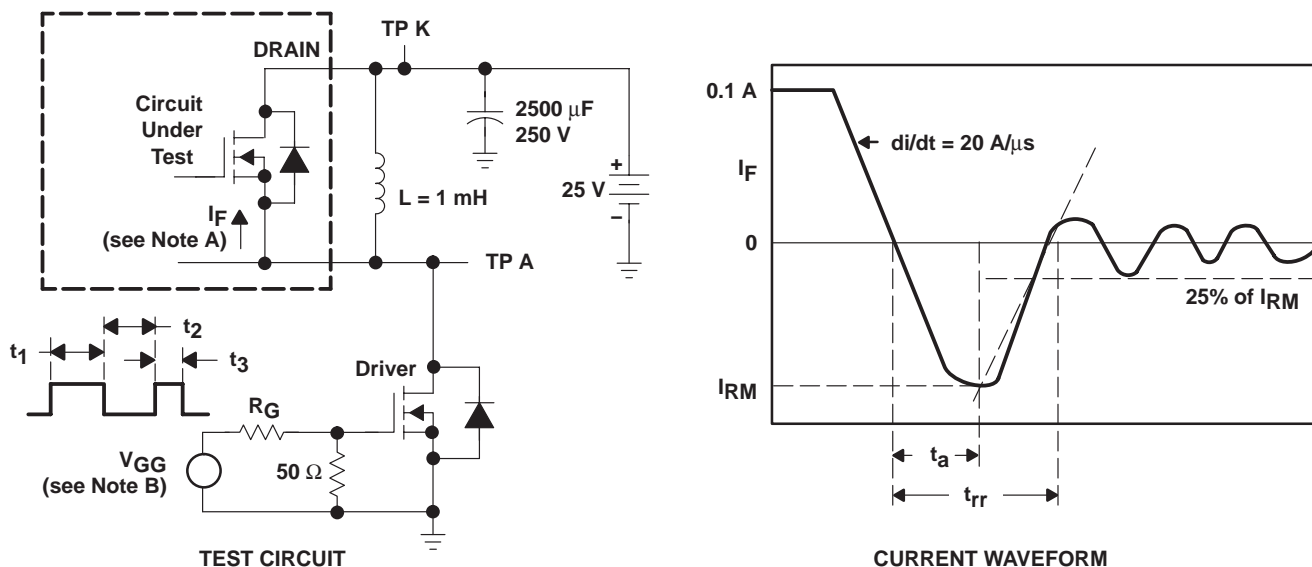
## PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The word generator has the following characteristics:  $t_r \leq 10 \text{ ns}$ ,  $t_f \leq 10 \text{ ns}$ ,  $t_w = 300 \text{ ns}$ , pulsed repetition rate (PRR) = 5 kHz,  $Z_O = 50 \Omega$ .  
B.  $C_L$  includes probe and jig capacitance.

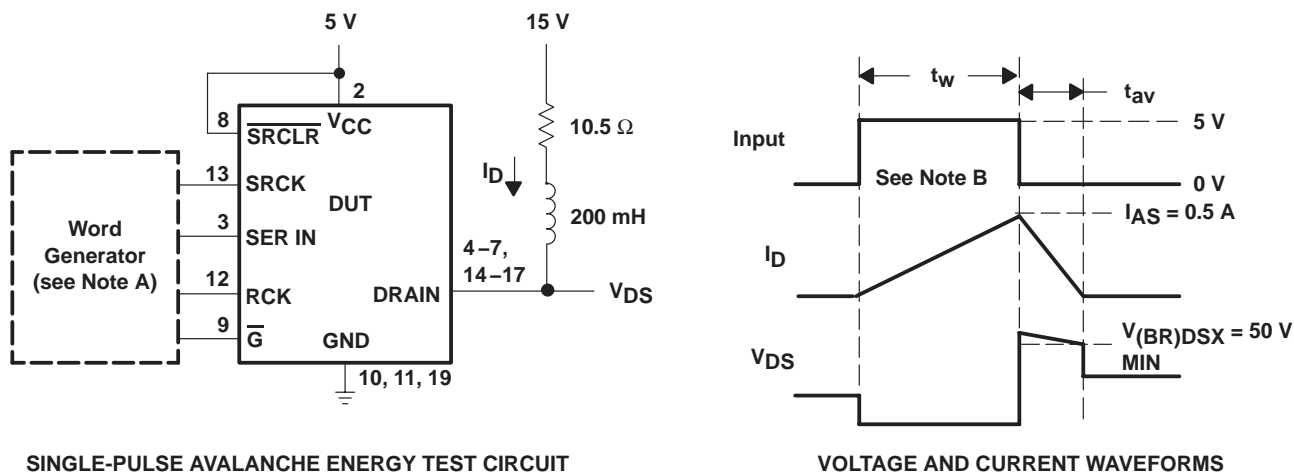
**Figure 2. Test Circuit, Switching Times, and Voltage Waveforms**

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The DRAIN terminal under test is connected to the TP K test point. All other terminals are connected together and connected to the TP A test point.  
 B. The  $V_{GG}$  amplitude and  $R_G$  are adjusted for  $di/dt = 20 \text{ A}/\mu\text{s}$ . A  $V_{GG}$  double-pulse train is used to set  $I_F = 0.1 \text{ A}$ , where  $t_1 = 10 \mu\text{s}$ ,  $t_2 = 7 \mu\text{s}$ , and  $t_3 = 3 \mu\text{s}$ .

Figure 3. Reverse-Recovery-Current Test Circuit and Waveforms of Source-to-Drain Diode



- NOTES: A. The word generator has the following characteristics:  $t_r \leq 10 \text{ ns}$ ,  $t_f \leq 10 \text{ ns}$ ,  $Z_O = 50 \Omega$ .  
 B. Input pulse duration,  $t_w$ , is increased until peak current  $I_{AS} = 0.5 \text{ A}$ .  
 Energy test level is defined as  $E_{AS} = I_{AS} \times V_{(BR)DSX} \times t_{AV}/2 = 30 \text{ mJ}$ .

Figure 4. Single-Pulse Avalanche Energy Test Circuit and Waveforms

# TPIC6B596 POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

## TYPICAL CHARACTERISTICS

PEAK AVALANCHE CURRENT  
vs  
TIME DURATION OF AVALANCHE

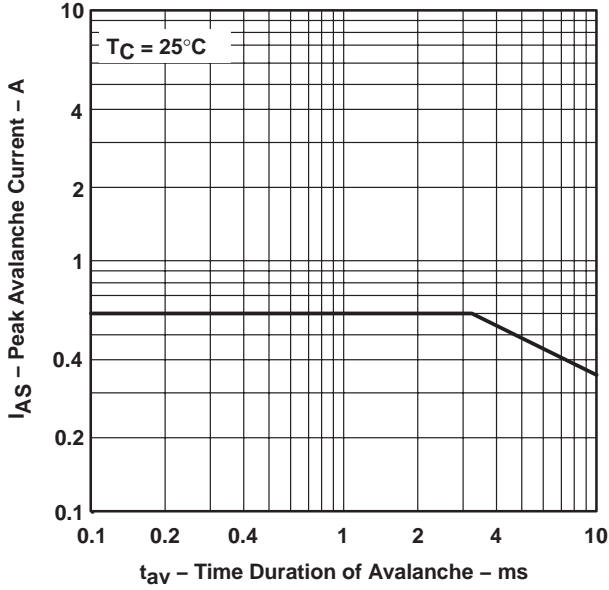


Figure 5

SUPPLY CURRENT  
vs  
FREQUENCY

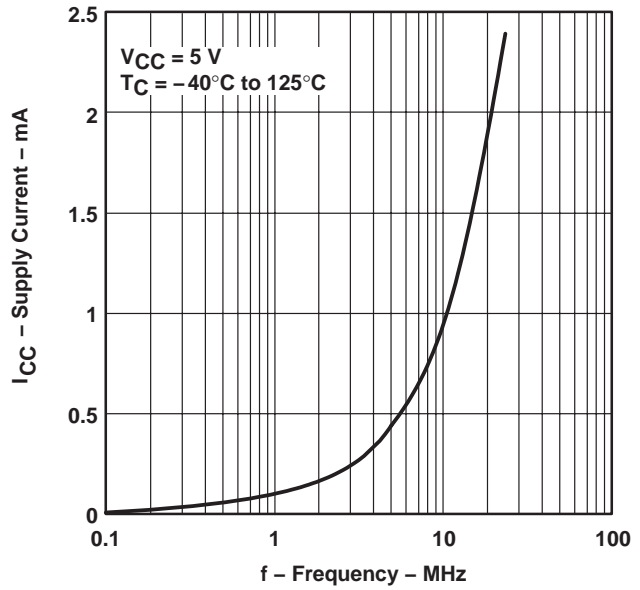


Figure 6

DRAIN-TO-SOURCE ON-STATE RESISTANCE  
vs  
DRAIN CURRENT

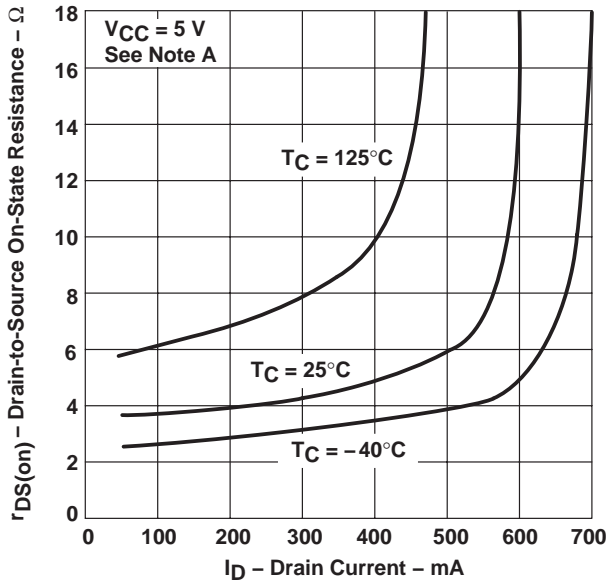


Figure 7

STATIC DRAIN-TO-SOURCE ON-STATE RESISTANCE  
vs  
LOGIC SUPPLY VOLTAGE

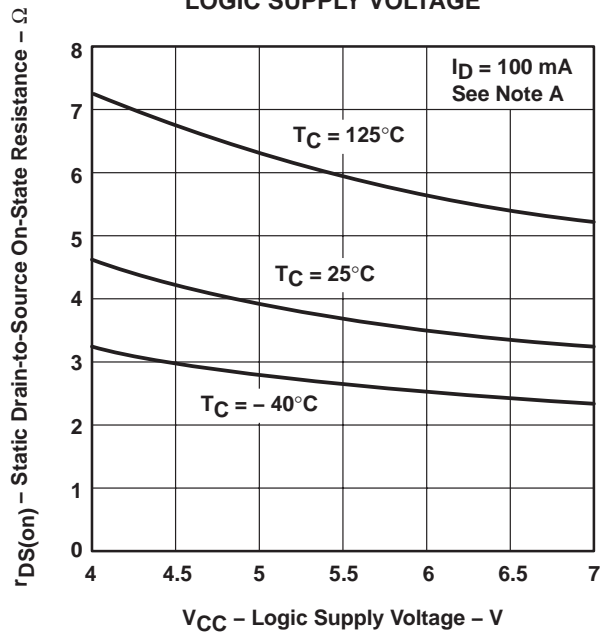


Figure 8



TYPICAL CHARACTERISTICS

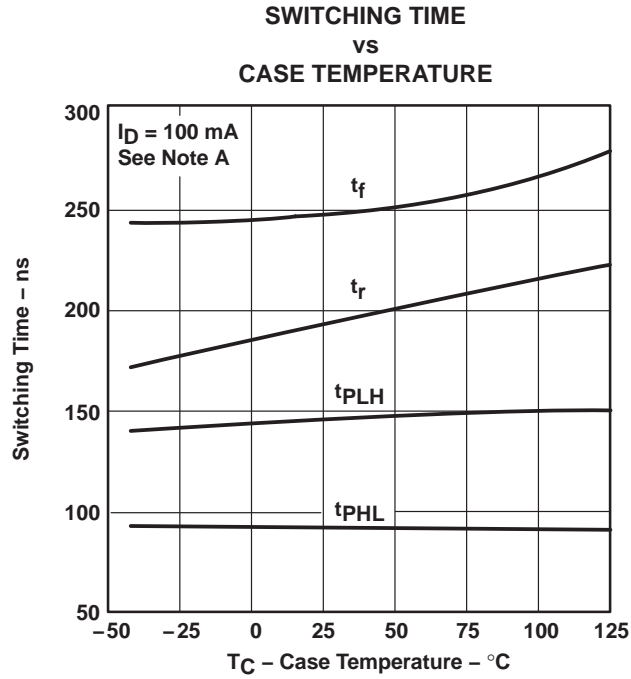


Figure 9

NOTE A: Technique should limit  $T_J - T_C$  to 10°C maximum.

# TPIC6B596 POWER LOGIC 8-BIT SHIFT REGISTER

SLIS095A – MARCH 2000 – REVISED MAY 2005

## THERMAL INFORMATION

MAXIMUM CONTINUOUS  
DRAIN CURRENT OF EACH OUTPUT  
vs  
NUMBER OF OUTPUTS CONDUCTING  
SIMULTANEOUSLY

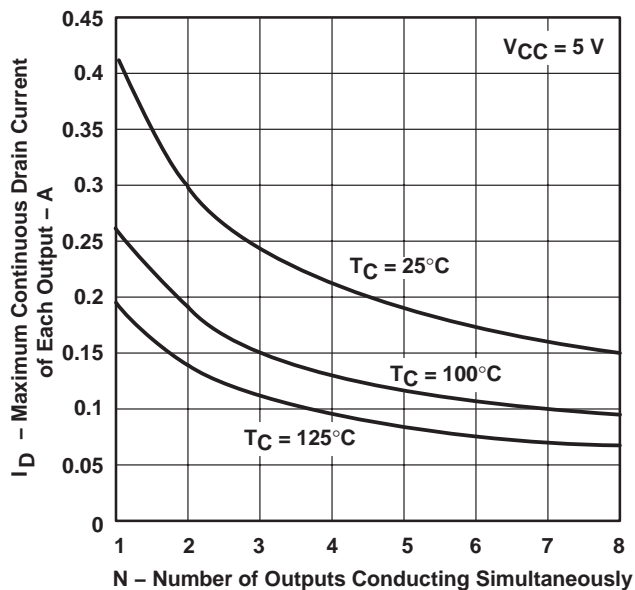


Figure 10

MAXIMUM PEAK DRAIN CURRENT  
OF EACH OUTPUT  
vs  
NUMBER OF OUTPUTS CONDUCTING  
SIMULTANEOUSLY

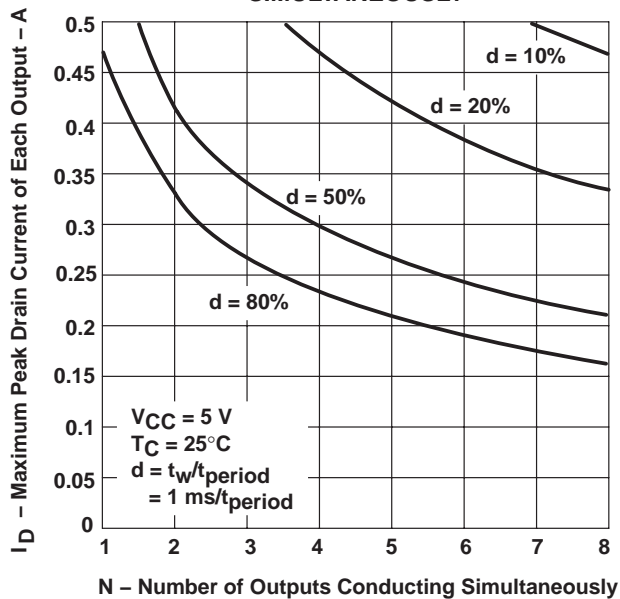


Figure 11

## Revision History

DATE	REV	PAGE	SECTION	DESCRIPTION
5/18/05	A	5	Figure 1	Changed SRCLR timing diagram
3/2000	*			Original reversion

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPIC6B596DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TPIC6B596	<a href="#">Samples</a>
TPIC6B596N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TPIC6B596N	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

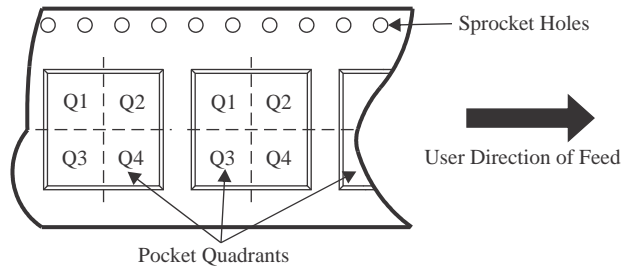
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


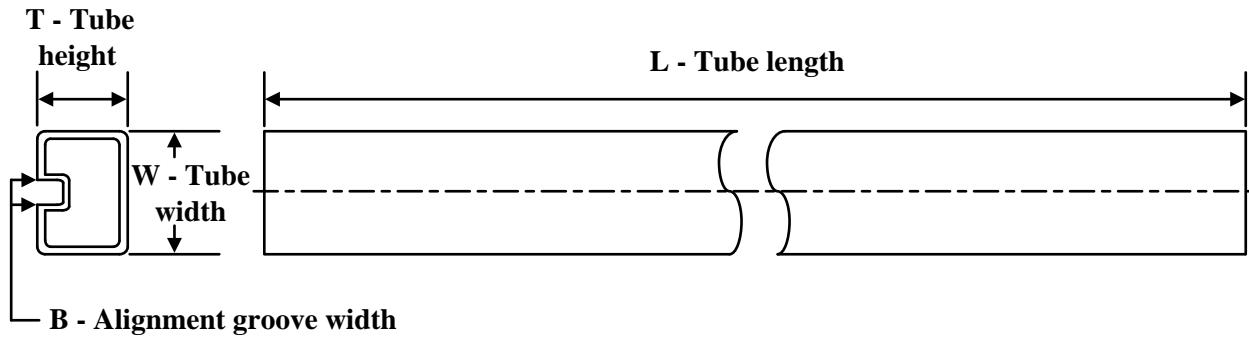
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPIC6B596DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPIC6B596DWR	SOIC	DW	20	2000	350.0	350.0	43.0

**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TPIC6B596N	N	PDIP	20	20	506	13.97	11230	4.32

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - D The 20 pin end lead shoulder width is a vendor option, either half or full width.

4040049/E 12/2002





# EXAMPLE BOARD LAYOUT

DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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[NLV14094BDTR2G](#) [NLV74HC589ADR2G](#) [AiP74HC595TA16.TR](#) [SN74LS295BN](#) [AIP74HC164TA14.TR](#) [TM74HC164](#) [74HC164D](#)  
[AiP74HC165SA16.TR](#) [74HC573D](#) [AiP74HC165TA16.TR](#) [XL74HC597-TS](#) [74HC164MT/TR](#) [XL74HC595TS](#) [74HC595DMT/TR](#)  
[CD4094DMT/TR](#) [74HC595D\(MS\)](#) [CD4094DM/TR](#) [74HC164D](#) [GN165D](#) [74HC595DM/TR](#) [AIP74HC595SA.TR](#) [XL4021B](#)  
[74HC164D\(MS\)](#) [74HC595MT/TR](#) [XL74HC165-TS](#) [74HC595D](#) [74HC595D](#) [74HC595D.](#) [74HCT595BQ](#) [RS595SXTSS16](#)  
[Aip74HC595SA16.TR](#) [SN74LS164DR-HXY](#) [74HC164DR](#) [RS595SXS16](#) [74HC165-HXY](#) [74HC595E](#) [RS164XQ](#) [GN74HC595D](#)  
[74HC164DRG](#) [XD74HC165](#) [SN74LV165AQWBQBRQ1](#) [AiP74HC4094SA16.TR](#) [HX74HC595IDRG](#)